

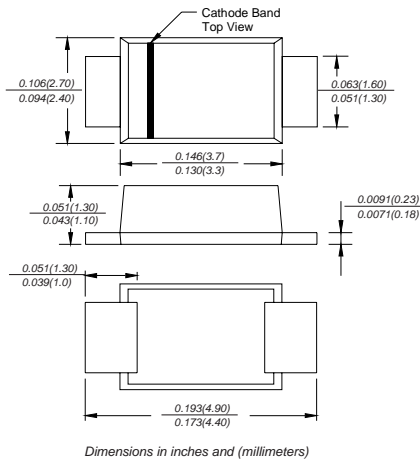


SS52F THRU SS5200F

SURFACE MOUNT SCHOTTKY BARRIER RECTIFIER

Reverse Voltage - 20 to 200 Volts Forward Current - 5.0 Ampere

SMAF



FEATURES

- ◆ The plastic package carries Underwriters Laboratory Flammability Classification 94V-0
- ◆ For surface mounted applications
- ◆ Metal silicon junction, majority carrier conduction
- ◆ Low power loss, high efficiency
- ◆ Built-in strain relief, ideal for automated placement
- ◆ High forward surge current capability
- ◆ High temperature soldering guaranteed: 260°C/10 seconds at terminals

MECHANICAL DATA

Case: JEDEC SMAF molded plastic body
Terminals: leads solderable per MIL-STD-750, Method 2026
Polarity: Color band denotes cathode end
Mounting Position: Any
Weight: 0.0018 ounce, 0.064 grams

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

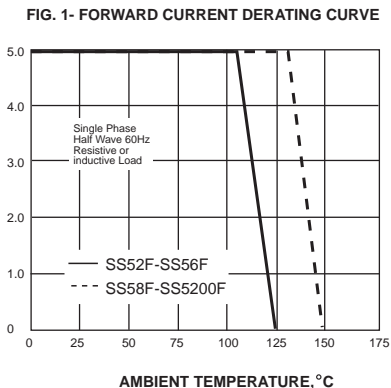
Ratings at 25°C ambient temperature unless otherwise specified.
 Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

TYPE NUMBER	SYMBOLS	SS52F	SS53F	SS54F	SS55F	SS56F	SS58F	SS510F	SS5150F	SS5200F	UNITS	
Maximum repetitive peak reverse voltage	V_{RRM}	20	30	40	50	60	80	100	150	200	VOLTS	
Maximum RMS voltage	V_{RMS}	14	21	28	35	42	56	70	105	140	VOLTS	
Maximum DC blocking voltage	V_{DC}	20	30	40	50	60	80	100	150	200	VOLTS	
Maximum average forward rectified current at T_L (see fig.1)	I_{AV}	5.0									Amp	
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I_{FSM}	150.0									Amps	
Maximum instantaneous forward voltage at 5.0A	V_F	0.55		0.70			0.85		0.95		Volts	
Maximum DC reverse current $T_A=25^\circ\text{C}$ at rated DC blocking voltage $T_A=100^\circ\text{C}$	I_R	0.5						0.2			mA	
		20.0			10			2.0				
Typical junction capacitance (NOTE 1)	C_J	200									pF	
Typical thermal resistance (NOTE 2)	$R_{\theta JA}$	50.0									°C/W	
Operating junction temperature range	T_J	-50 to +125					-50 to +150					°C
Storage temperature range	T_{STG}	-50 to +150									°C	

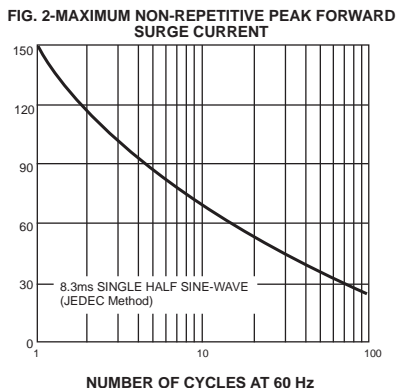
Note: 1. Measured at 1MHz and applied reverse voltage of 4.0V D.C.
 2. P.C.B. mounted with 0.2x0.2" (5.0x5.0mm) copper pad areas

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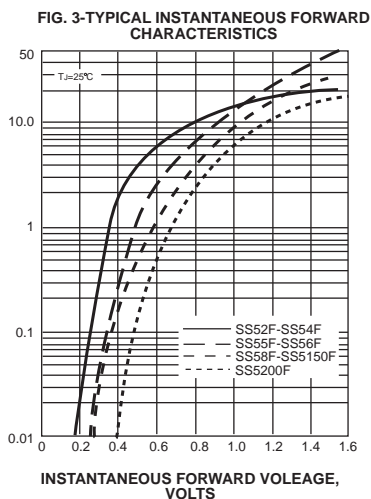
AVERAGE FORWARD RECTIFIED CURRENT,
AMPERES



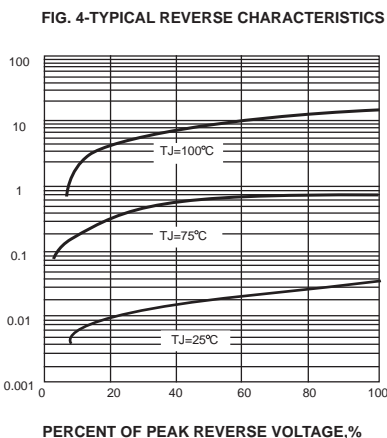
PEAK FORWARD SURGE CURRENT,
AMPERES



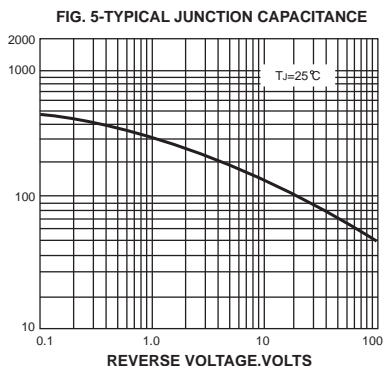
INSTANTANEOUS FORWARD
CURRENT, AMPERES



INSTANTANEOUS REVERSE CURRENT,
MILLIAMPERES



JUNCTION CAPACITANCE, pF



TRANSIENT THERMAL IMPEDANCE,
°C/W

